

FML20N50ES

FUJI POWER MOSFET

Super FAP-E³ series

N-CHANNEL SILICON POWER MOSFET

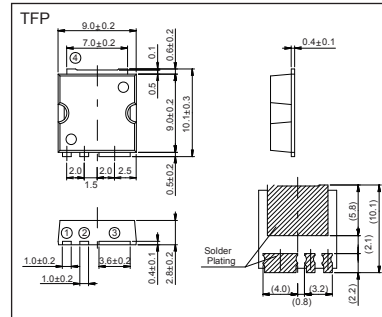
Features

- Maintains both low power loss and low noise
- Lower R_{DS(on)} characteristic
- More controllable switching dv/dt by gate resistance
- Smaller V_{GS} ringing waveform during switching
- Narrow band of the gate threshold voltage (4.2±0.5V)
- High avalanche durability

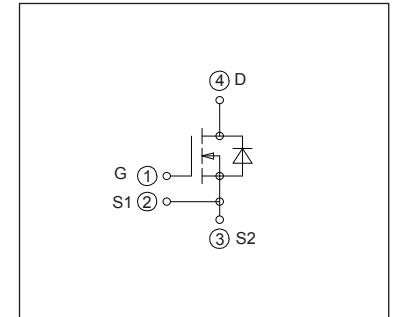
Applications

- Switching regulators
- UPS (Uninterruptible Power Supply)
- DC-DC converters

Outline Drawings [mm]



Equivalent circuit schematic



Maximum Ratings and Characteristics

Absolute Maximum Ratings at T_c=25°C (unless otherwise specified)

Description	Symbol	Characteristics	Unit	Remarks
Drain-Source Voltage	V _{DS}	500	V	
	V _{DSSX}	500	V	V _{GS} = -30V
Continuous Drain Current	I _D	±20	A	
Pulsed Drain Current	I _{DP}	±80	A	
Gate-Source Voltage	V _{GS}	±30	V	
Repetitive and Non-Repetitive Maximum Avalanche Current	I _{AR}	20	A	Note*1
Non-Repetitive Maximum Avalanche Energy	E _{AS}	582.5	mJ	Note*2
Repetitive Maximum Avalanche Energy	E _{AR}	9.5	mJ	Note*3
Peak Diode Recovery dv/dt	dV/dt	4.6	kV/μs	Note*4
Peak Diode Recovery -di/dt	-di/dt	100	A/μs	Note*5
Maximum Power Dissipation	P _D	2.16	W	T _a =25°C
		95		T _c =25°C
Operating and Storage Temperature range	T _{ch}	150	°C	
	T _{stg}	-55 to + 150	°C	
Isolation Voltage	V _{ISO}	2	kVrms	t = 60sec, f = 60Hz

Electrical Characteristics at T_c=25°C (unless otherwise specified)

Description	Symbol	Conditions	min.	typ.	max.	Unit
Drain-Source Breakdown Voltage	BV _{DSS}	I _D =250μA, V _{GS} =0V	500	-	-	V
Gate Threshold Voltage	V _{GS} (th)	I _D =250μA, V _{DS} =V _{GS}	3.7	4.2	4.7	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =500V, V _{GS} =0V	-	-	25	μA
		V _{DS} =400V, V _{GS} =0V	-	-	250	
Gate-Source Leakage Current	I _{GSS}	V _{GS} =±30V, V _{DS} =0V	-	10	100	nA
Drain-Source On-State Resistance	R _{DS} (on)	I _D =10A, V _{GS} =10V	-	0.27	0.31	Ω
Forward Transconductance	g _{fs}	I _D =10A, V _{DS} =25V	5	10	-	S
Input Capacitance	C _{iss}	V _{DS} =25V	-	2100	3150	pF
Output Capacitance	C _{oss}	V _{GS} =0V	-	250	375	
Reverse Transfer Capacitance	C _{rss}	f=1MHz	-	15	22.5	
Turn-On Time	td(on)	V _{cc} =300V	-	40	60	ns
	tr	V _{GS} =10V	-	38	57	
Turn-Off Time	td(off)	I _D =10A	-	85	127.5	
	tf	R _{GS} =15Ω	-	17	25.5	
Total Gate Charge	Q _G	V _{cc} =250V	-	57	85.5	nC
Gate-Source Charge	Q _{GS}	I _D =20A	-	21	31.5	
Gate-Drain Charge	Q _{GD}	V _{GS} =10V	-	21	31.5	
Gate-Drain Crossover Charge	Q _{SW}		-	10	15	
Avalanche Capability	I _{AV}	L=1.07mH, T _{ch} =25°C	20	-	-	A
Diode Forward On-Voltage	V _{SD}	I _F =20A, V _{GS} =0V, T _{ch} =25°C	-	0.90	1.35	V
Reverse Recovery Time	t _{rr}	I _F =20A, V _{GS} =0V	-	0.5	-	μs
Reverse Recovery Charge	Q _{rr}	-di/dt=100A/μs, T _{ch} =25°C	-	7.0	-	μC

Thermal Characteristics

Description	Symbol	Test Conditions	min.	typ.	max.	Unit
Thermal resistance	R _{th} (ch-c)	Channel to Case			1.320	°C/W
	R _{th} (ch-a)	Channel to Ambient			58.0	°C/W

Note *1 : T_{ch}≤150°C.

Note *2 : Stating T_{ch}=25°C, I_{AS}=8A, L=16.7mH, V_{CC}=50V, R_G=50Ω.

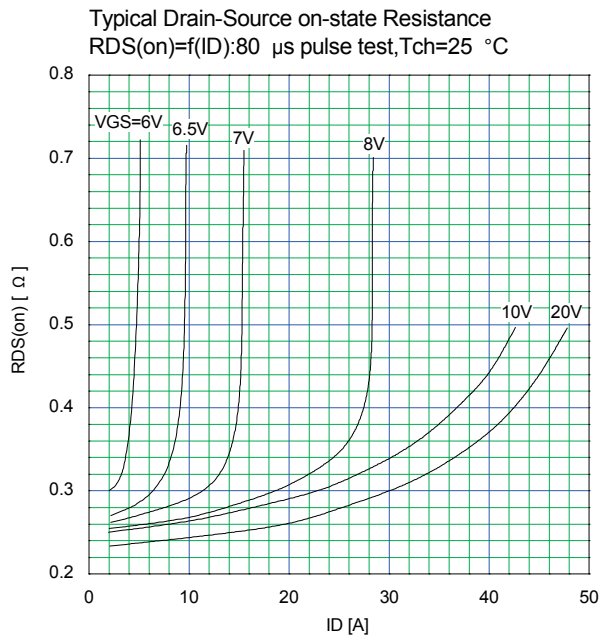
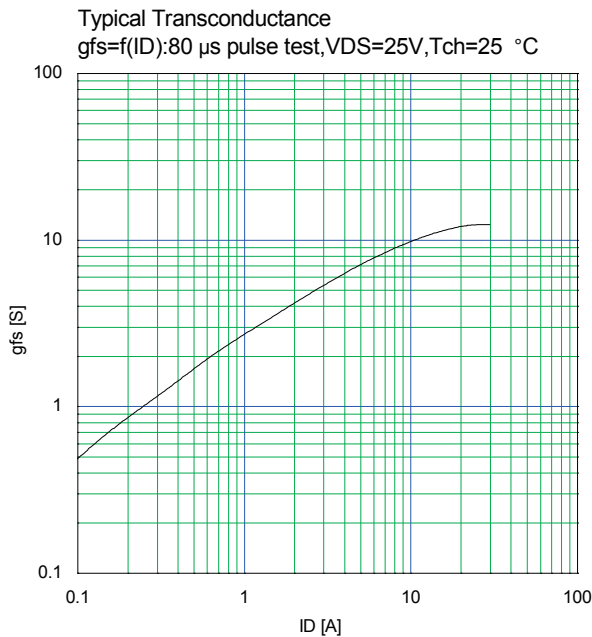
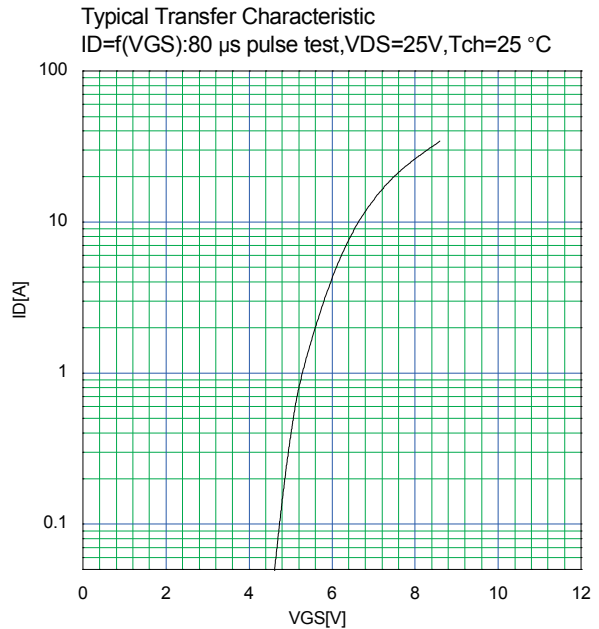
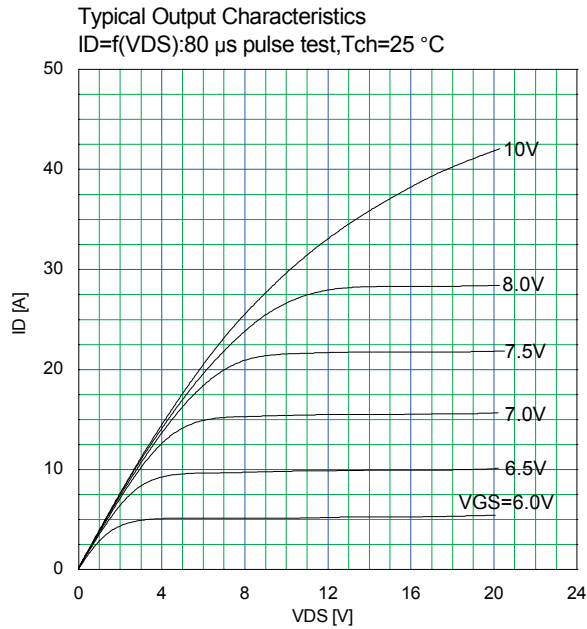
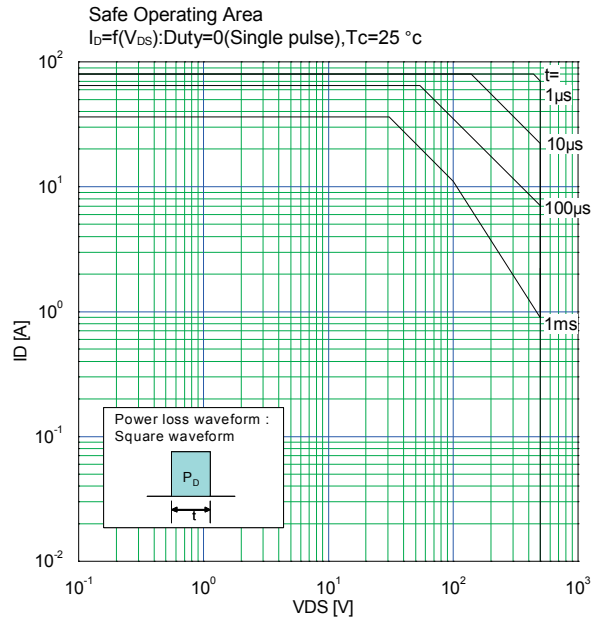
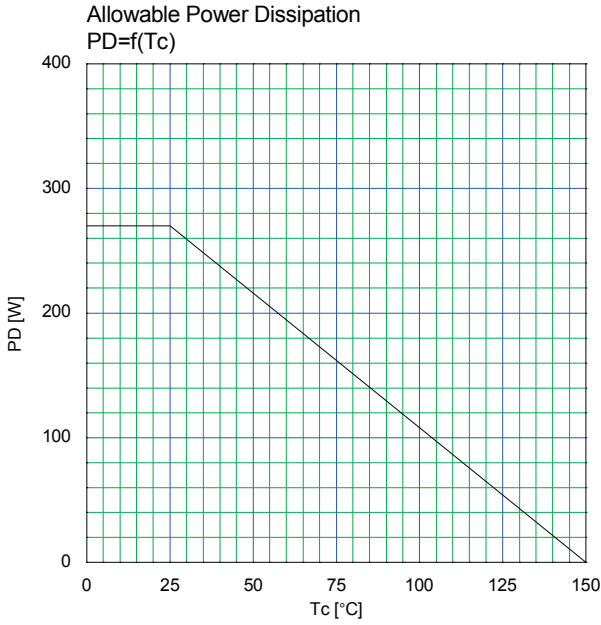
E_{AS} limited by maximum channel temperature and avalanche current.
See to 'Avalanche Energy' graph.

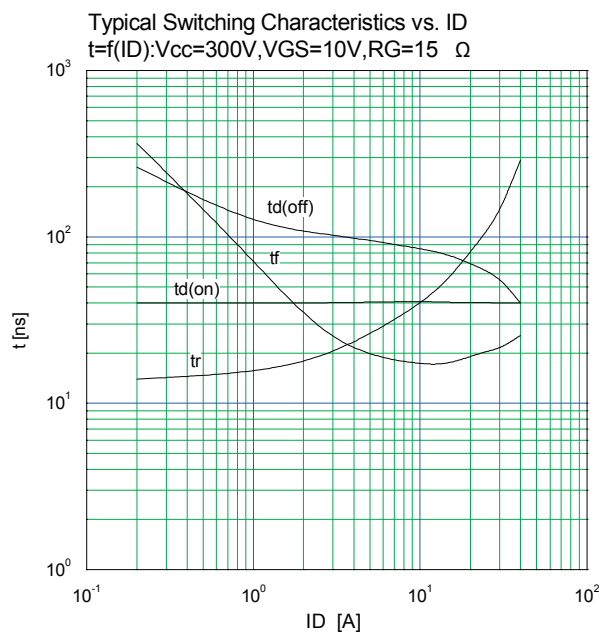
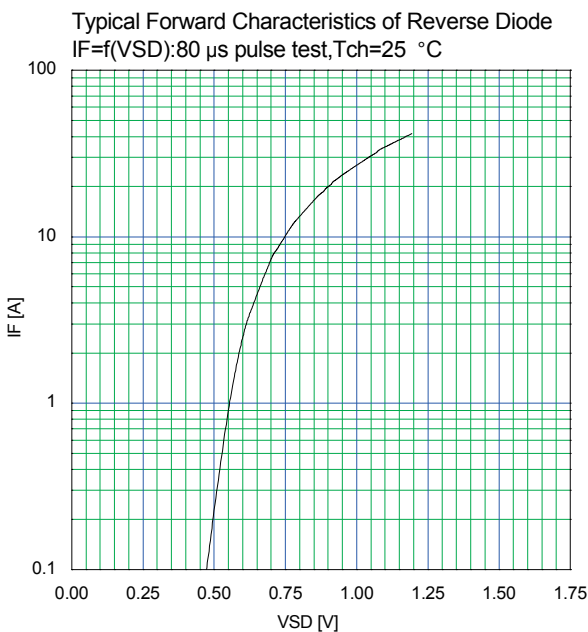
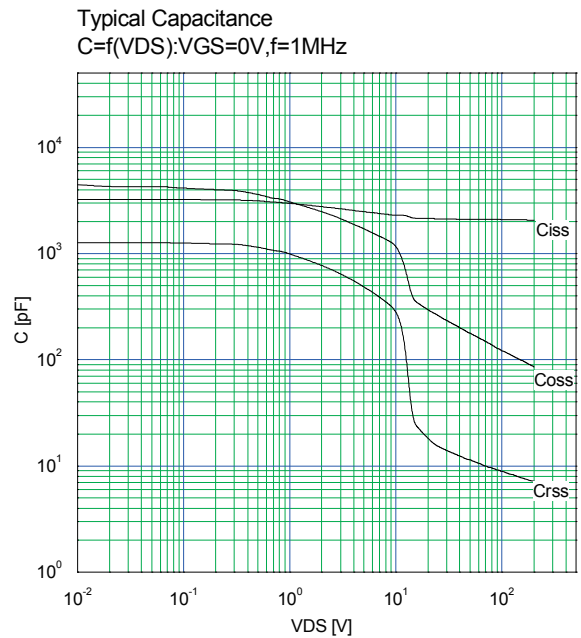
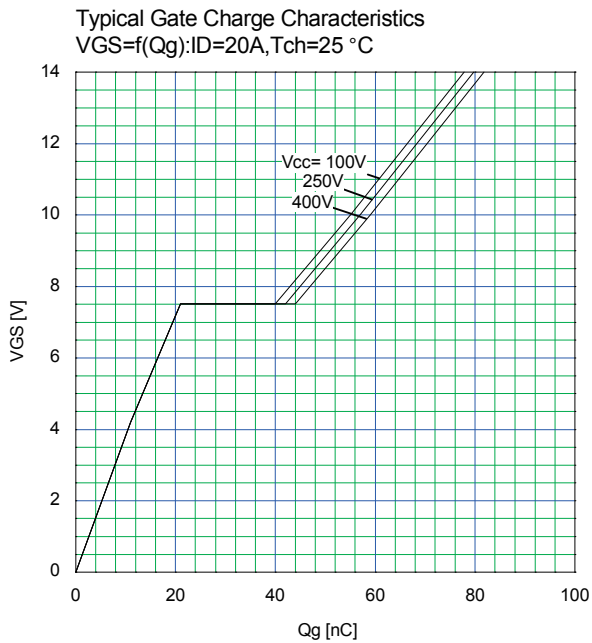
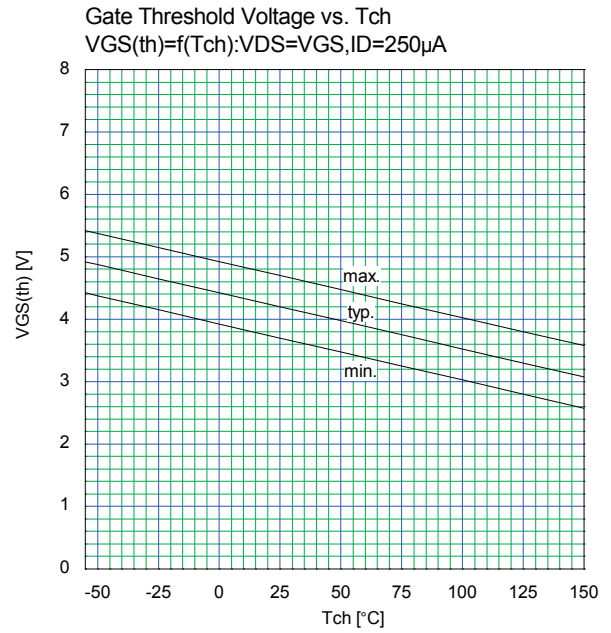
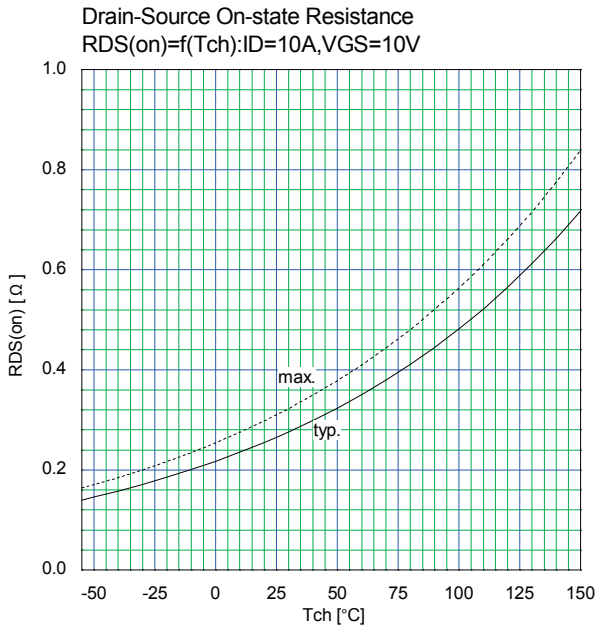
Note *3 : Repetitive rating : Pulse width limited by maximum channel temperature.

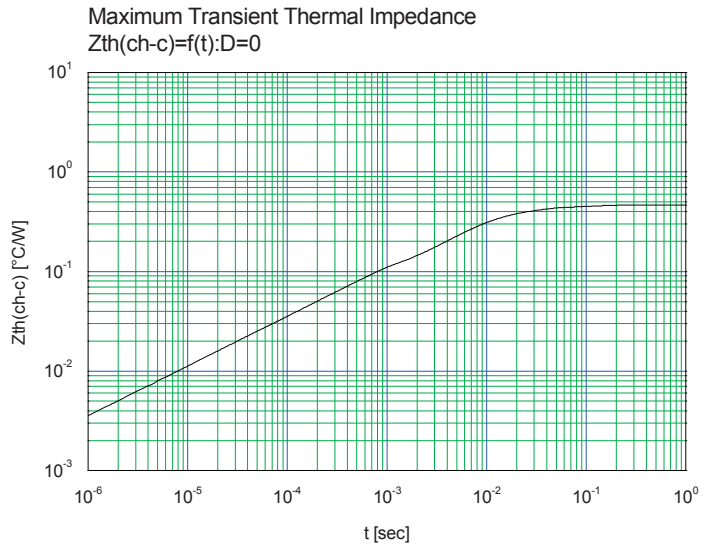
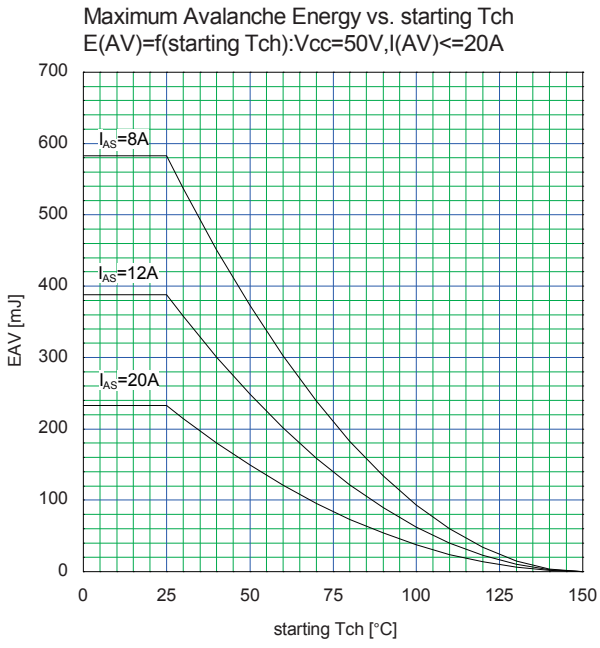
See to the 'Transient Thermal Impedance' graph.

Note *4 : I_F≤I_D, -di/dt=100A/μs, V_{CC}≤BV_{DSS}, T_{ch}≤150°C.

Note *5 : I_F≤I_D, dv/dt=4.6kV/μs, V_{CC}≤BV_{DSS}, T_{ch}≤150°C.







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